

RJH1CF4RDPQ-80

Silicon N Channel IGBT
High Speed Power Switching

R07DS0354EJ0100

Rev.1.00

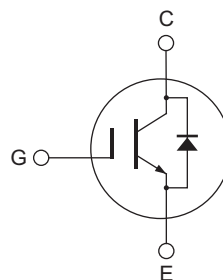
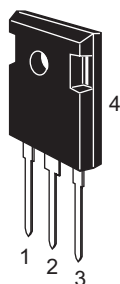
May 12, 2011

Features

- Voltage resonance circuit use
- Reverse conducting IGBT with monolithic body diode
- High efficiency device for induction heating
- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 2.0 \text{ V typ. (at } I_C = 20 \text{ A, } V_{GE} = 15 \text{ V, } T_j = 25^\circ\text{C)}$
- Gate to emitter voltage rating $\pm 30 \text{ V}$
- Pb-free lead plating

Outline

RENESAS Package code: PRSS0003ZE-A
(Package name: TO-247)



1. Gate
2. Collector
3. Emitter
4. Collector

Absolute Maximum Ratings

($T_c = 25^\circ\text{C}$)

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V_{CES}	1200	V
Gate to emitter voltage		V_{GES}	± 30	V
Collector current	$T_c = 25^\circ\text{C}$	I_C	40	A
	$T_c = 100^\circ\text{C}$	I_C	20	A
Collector peak current		$i_{c(peak)}$ ^{Note1}	80	A
Collector to emitter diode forward current		i_{DF}	15	A
Collector dissipation		P_C	156.2	W
Junction to case thermal impedance		θ_{j-c}	0.8	$^\circ\text{C/W}$
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. Pulse width limited by safe operating area.

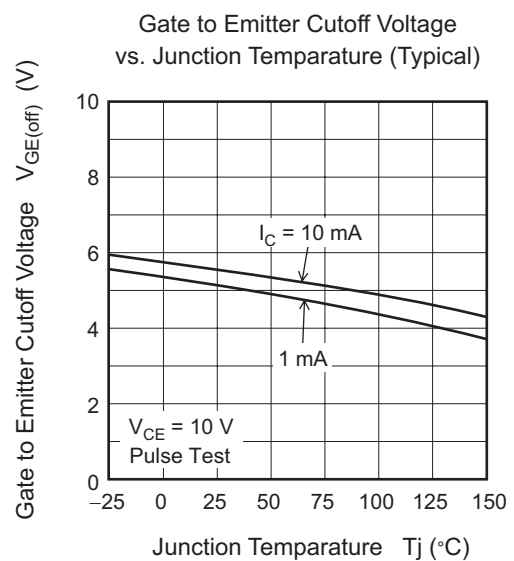
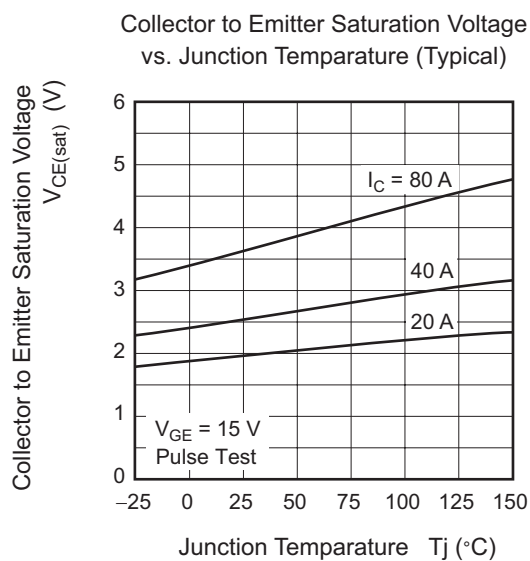
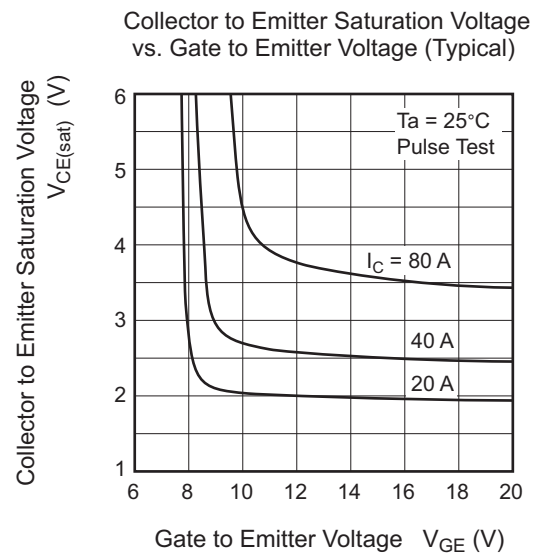
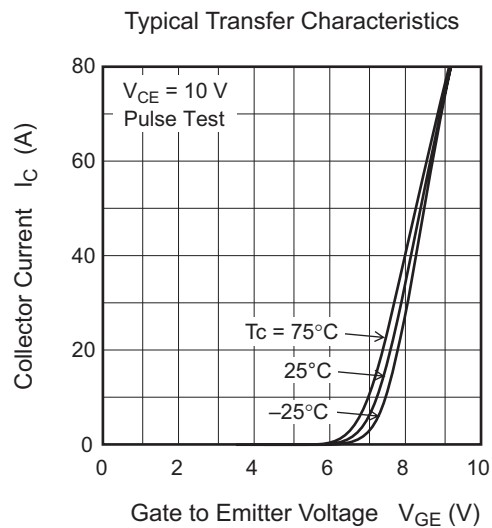
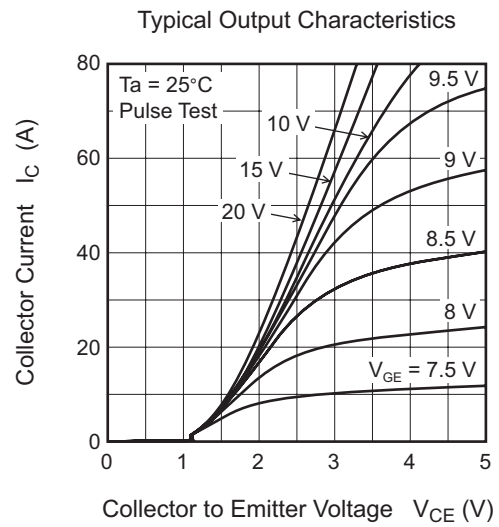
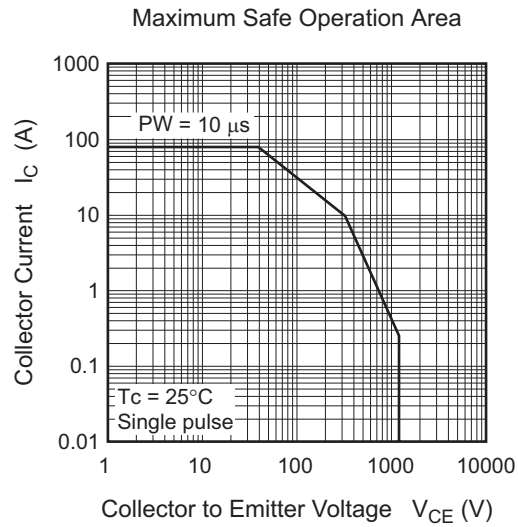
Electrical Characteristics

(T_j = 25°C)

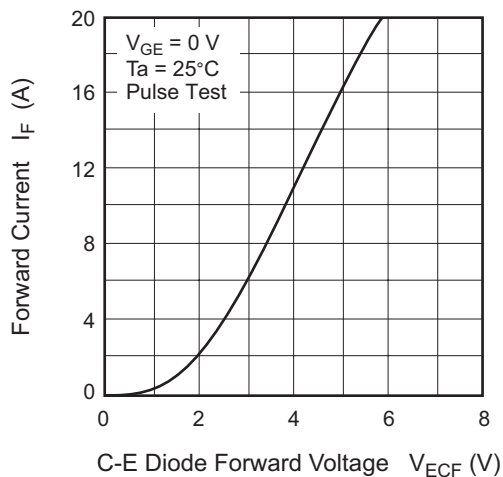
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	—	—	100	μA	V _{CE} = 1200 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	—	—	±0.1	μA	V _{GE} = ±30 V, V _{CE} = 0
Gate to emitter cutoff voltage	V _{GE(off)}	3.5	5.0	7.0	V	V _{CE} = 10V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}	—	2.0	2.5	V	I _C = 20 A, V _{GE} = 15V ^{Note2}
		—	2.5	—	V	I _C = 40 A, V _{GE} = 15V ^{Note2}
Input capacitance	C _{ies}	—	1027	—	pF	V _{CE} = 25 V
Output capacitance	C _{oes}	—	24	—	pF	V _{GE} = 0 V
Reverse transfer capacitance	C _{res}	—	16	—	pF	f = 1 MHz
Switching time	t _{d(on)}	—	40	—	ns	I _C = 20 A
	t _r	—	55	—	ns	V _{GE} = 15 V, V _{CE} = 600 V
	t _{d(off)}	—	87	—	ns	R _g = 5 Ω ^{Note2}
	t _f	—	300	—	ns	Resistive Load
C-E diode forward voltage	V _F	—	4.2	5.4	V	I _F = 10 A ^{Note2}

Notes: 2. Pulse test

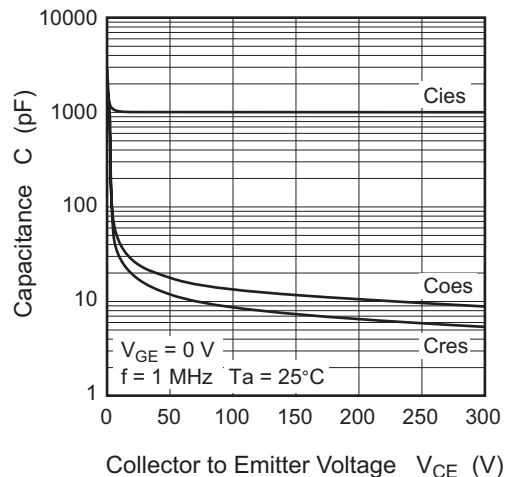
Main Characteristics



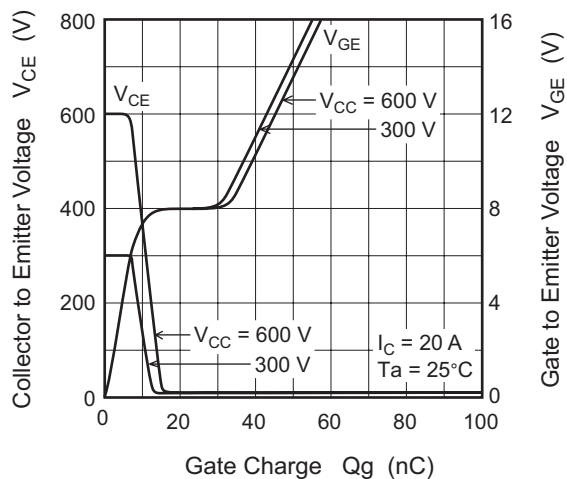
Forward Current vs. Forward Voltage (Typical)



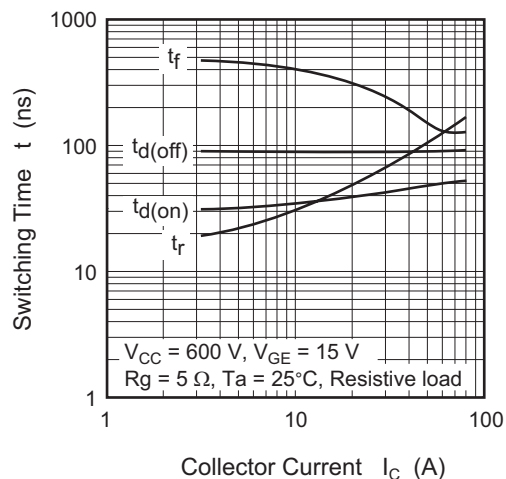
Typical Capacitance vs. Collector to Emitter Voltage



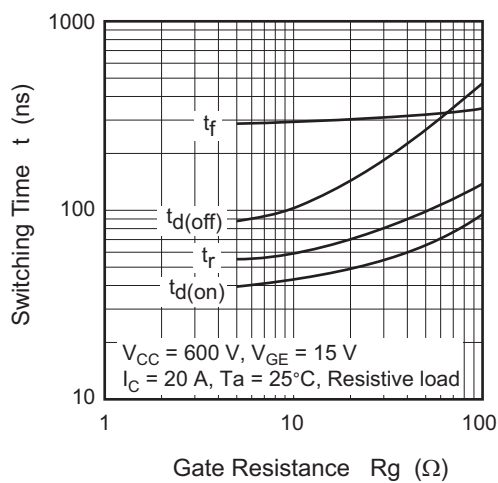
Dynamic Input Characteristics (Typical)



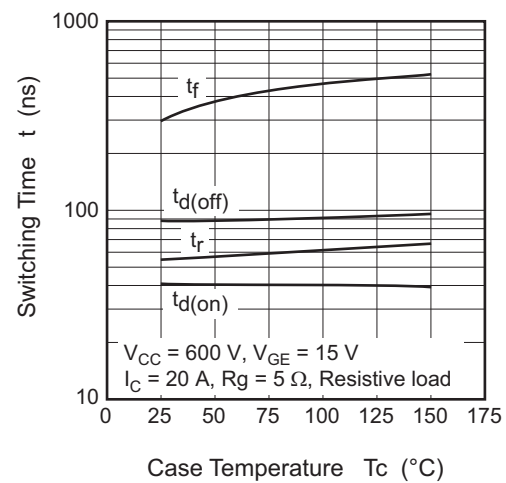
Switching Characteristics (Typical) (1)

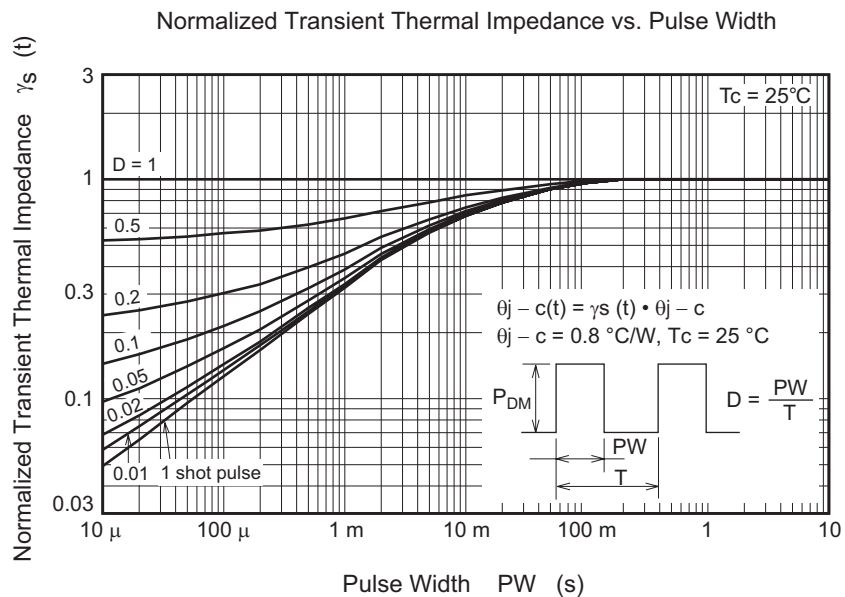


Switching Characteristics (Typical) (2)

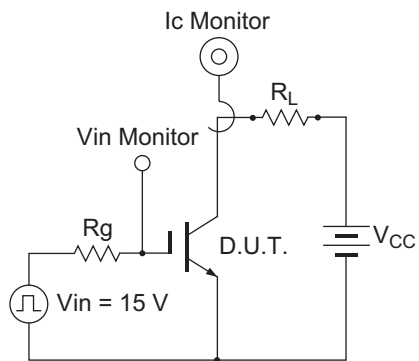


Switching Characteristics (Typical) (3)

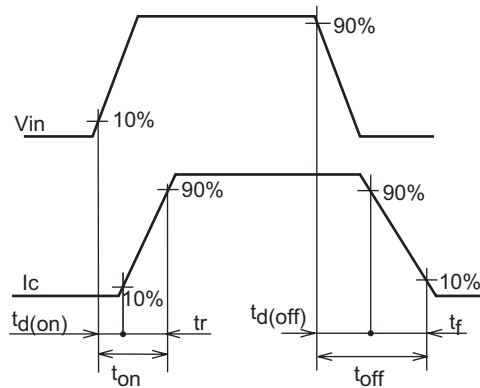




Switching Time Test Circuit



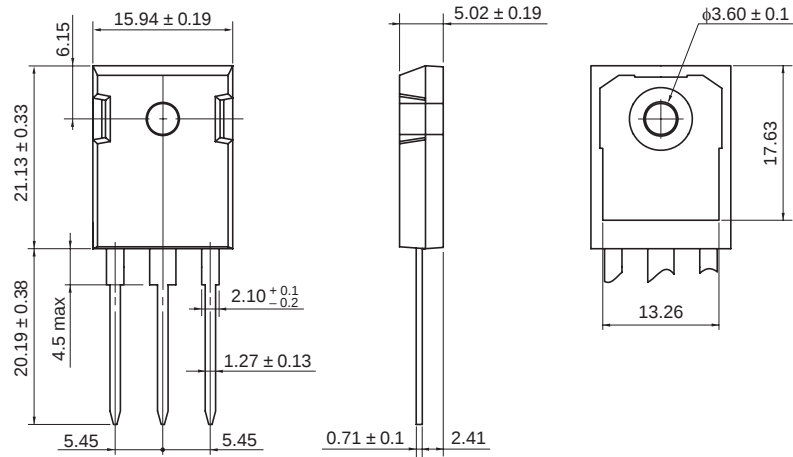
Waveform



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-247	—	PRSS0003ZE-A	—	6.0g

Unit: mm



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CF4RDPQ-80-T2	450 pcs	Box (Tube)

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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
1 harbourFront Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: +65-6213-0200, Fax: +65-6278-8001

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
11F., Samik Laved' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141